NSN 5961-01-444-8192

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-444-8192 **Inclosure Material:** Glass **Overall Length:** 0.175 inches **Overall Diameter:** 0.080 inches **Function For Which Designed:** Zener diode **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.9 regulator voltage **Voltage Tolerance In Percent:** -2.0/+2.0 **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0